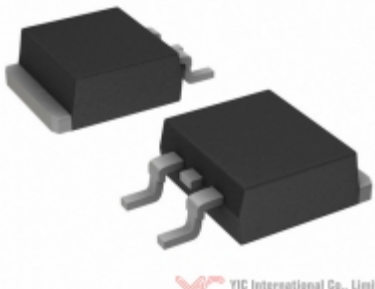

	<h2 style="color: #E67E22;">FQB9N08LTM</h2>
 <p style="font-size: small;">Image may be representation. See specs for product details.</p>	<b>Hersteller-Teilenummer:</b> <span style="color: #3498DB;">FQB9N08LTM</span>
	<b>Hersteller / Marke:</b> <span style="color: #3498DB;">Fairchild/ON Semiconductor</span>
	<b>Teil der Beschreibung:</b> <span style="color: #3498DB;">MOSFET N-CH 80V 9.3A D2PAK</span>
	<b>Datenblätter:</b>  <span style="color: #3498DB;">FQB9N08LTM.pdf</span>
	<b>RoHs Status:</b> <span style="color: #3498DB;">Bleifrei / RoHS-konform</span>
	<b>Lagerzustand:</b> <span style="color: #3498DB;">New original, 1546 pcs Stock Available.</span>
<b>Liefern von:</b> <span style="color: #3498DB;">Hong Kong</span>	
<b>Versandweg:</b> <span style="color: #3498DB;">DHL/Fedex/TNT/UPS/EMS</span>	

### Spezifikationen

Teilenummer	FQB9N08LTM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 80V 9.3A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	1546 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.75W (Ta), 40W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	80V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	9.3A (Tc)
Rds On (Max) @ Id, Vgs	210 mOhm @ 4.65A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	6.1nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	280pF @ 25V
Verpackung	Tape & Reel (TR)

FQB9N08LTM ist neu im Original, Suche FQB9N08LTM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB9N08LTM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB9N08LTM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <b>FQB8P10TM-NL</b> VB FQB8P10TM-NL VB	 <b>FQB9N15TM</b> Fairchild/ON Semiconductor MOSFET N-CH 150V 9A D2PAK	 <b>FQB9N08TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 80V 9.3A D2PAK	 <b>FQB9N08L</b> VB FQB9N08L VB
 <b>FQB9N15TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V 9A D2PAK	 <b>FQB9N08TM</b> Fairchild/ON Semiconductor MOSFET N-CH 80V 9.3A D2PAK	 <b>FQB95N03L</b> FAIRCHI FAIRCHI SOT-263	 <b>FQB9N25</b> Fairchild/ON Semiconductor FQB9N25 FAIRCHILD

### heiße Teile

Mehr

⚙ FQB6N70TM	↔ FQB6N90TM	⇒ FQB6N90TM_AM002	D FQB6N90TM_AM002	↔ FQB7042FB
⊖ FQB7045FB	⚙ FQB70N03	D FQB70N06	⇒ FQB70N08	↔ FQB70N10TM
⚙ FQB7N10L	⊖ FQB7N20L	⚙ FQB7N60TM	↔ FQB7N60TM	↔ FQB7N65C
D FQB7N65CTM	⚙ FQB7N65CTM	⊖ FQB7P20TM	⚙ FQB7P20TM	↔ FQB85N06
⇒ FQB85N06TM	↔ FQB8N25TM	⚙ FQB8N25TM	⊖ FQB8N60C	↔ FQB8N60CFTM
↔ FQB8N60CFTM	⇒ FQB8N60CTM	D FQB8N60CTM	⚙ FQB8N60TM	⊖ FQB8N90CTM
⚙ FQB8N90CTM	D FQB8P10TM	⇒ FQB8P10TM	↔ FQB8P10TM-NL	↔ FQB9N08L
⊖ FQB9N08LTM	⚙ FQB9N25C	↔ FQB9N25CTM	⇒ FQB9N25CTM	↔ FQB9N25TM
⚙ FQB9N25TM	⊖ FQB9N50C	⚙ FQB9N50CFTM	D FQB9N50CFTM	↔ FQB9N50CTM
↔ FQB9N50CTM	⚙ FQB9N50TM	⊖ FQB9N50TM	⚙ FQB9P25TM	↔ FQB9P25TM

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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